

1. General description

Planar passivated high commutation three quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. This "series BT" triac will commutate the full RMS current at the maximum rated junction temperature $(T_{j(max)} = 150 \text{ °C})$ without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

2. Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt
- High junction operating temperature capability
- High voltage capability
- Least sensitive gate for highest noise immunity
- · Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only

3. Applications

- Applications subject to high temperature
- Heating controls
- High power motor control
- High power switching

4. Quick reference data

| Table 1. Quic | k reference data | | | | | |
|---------------------|--|--|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{DRM} | repetitive peak off- state voltage | | - | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 122 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 20 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u> | - | - | 200 | A |
| | | full sine wave; $T_{j(init)} = 25 \text{ °C};$ t _p = 16.7 ms | - | - | 220 | A |
| Tj | junction temperature | | - | - | 150 | °C |
| Static chara | cteristics | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C | - | 10 | 50 | mA |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|-----|-----|------|------|
| | | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C | - | 10 | 50 | mA |
| | | V_D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C | - | 10 | 50 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C | - | 10 | 100 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C | - | - | 40 | mA |
| V _T | on-state voltage | I _T = 10 A; T _j = 25 °C | - | 1.3 | 1.65 | V |
| Dynamic char | acteristics | · | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 200 | - | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | $V_{\rm D}$ = 400 V; T _j = 95 °C; dI _{com} /dt = 3.6 A/ ms; I_T = 8 A; gate open circuit | 10 | - | - | V/µs |

5. Pinning information

| Table 2. I | Pinning inf | formation | | |
|------------|-------------|-----------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | T2-T1 |
| 2 | T2 | main terminal 2 | | sym051 |
| 3 | G | gate | | Symoor |
| mb | Τ2 | mounting base; main terminal 2 | TO-220AB (SOT78) | |

6. Ordering information

| Table 3. Ordering infor | mation | | | | | |
|-------------------------|----------|--|---------|--|--|--|
| Type number | Package | | | | | |
| | Name | Description | Version | | | |
| BTA420-800BT | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 | | | |



7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--|---|-----|-----|------|
| V _{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 122 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | 20 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; Fig. 4; Fig. 5 | - | 200 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | 220 | А |
| l ² t | I ² t for fusing | t _p = 10 ms; sine-wave pulse | - | 200 | A²s |
| dl _T /dt | rate of rise of on-state current | I _G = 100 mA | - | 100 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 150 | °C |

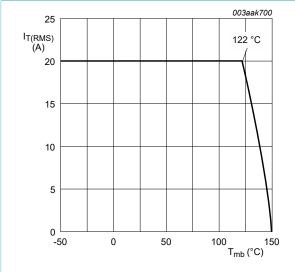
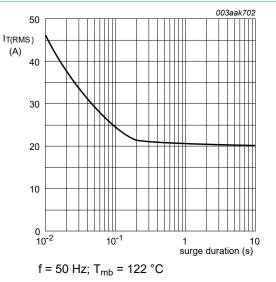


Fig. 1. RMS on-state current as a function of mounting base temperature; maximum values





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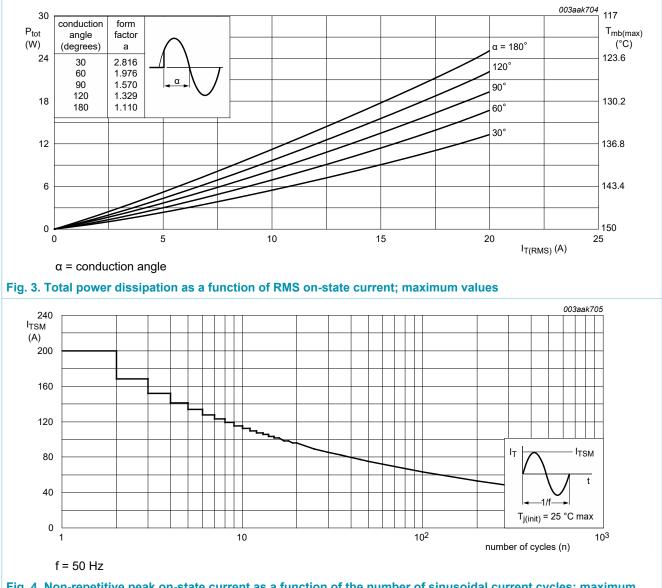
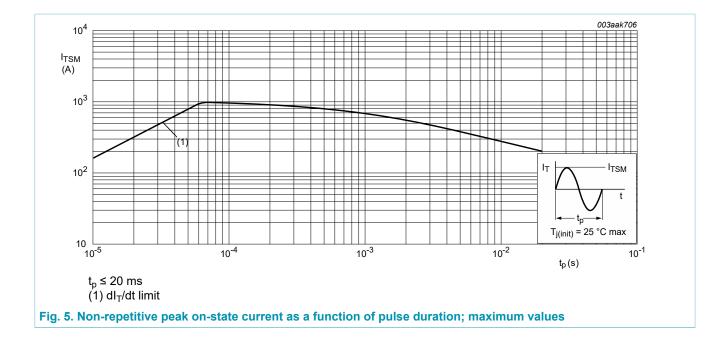


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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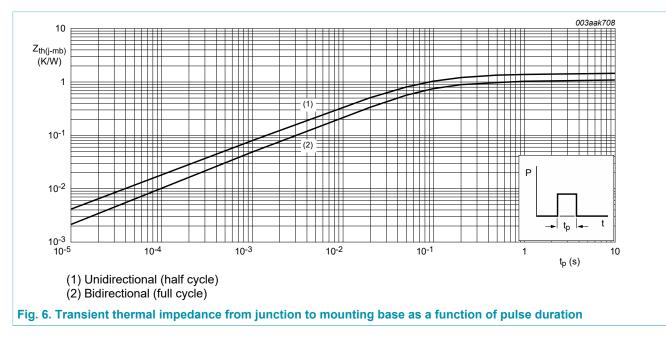




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8. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|--|---------------------------|-----|-----|-----|------|
| R _{th(j-mb)} | thermal resistance from junction to mounting base | full cycle; <u>Fig. 6</u> | - | - | 1.1 | K/W |
| | | half cycle; <u>Fig. 6</u> | - | - | 1.5 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient free air | in free air | - | 60 | - | K/W |



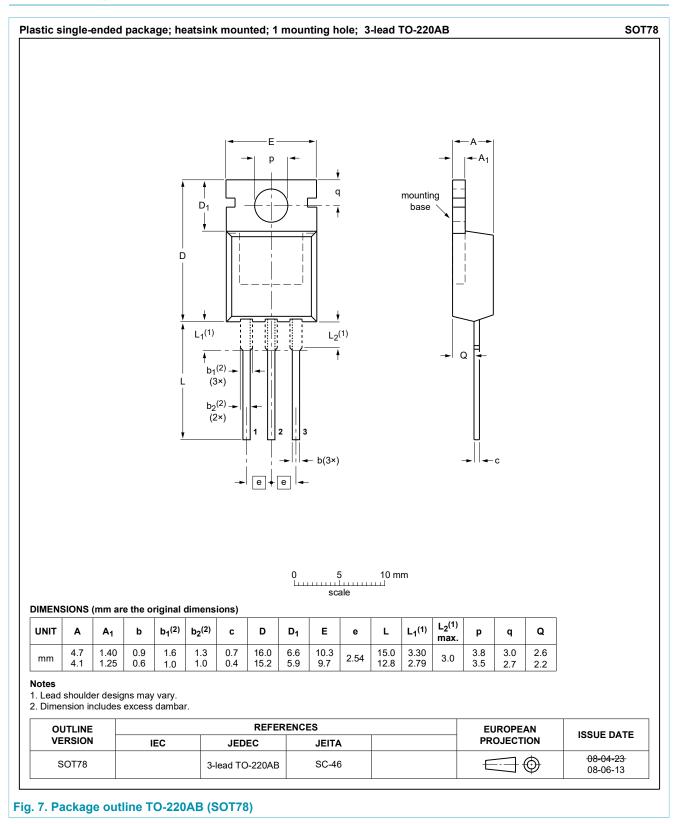
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9. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|------|-----|------|------|
| Static chara | octeristics | · · · · · | | | | |
| I _{GT} | gate trigger current | V_D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C | - | 10 | 50 | mA |
| | | V_D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C | - | 10 | 50 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C | - | 10 | 50 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C | - | 10 | 100 | mA |
| ΙL | latching current | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+}; $ T _j = 25 °C | - | - | 45 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-}; $ T _j = 25 °C | - | - | 60 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-}; $ T _j = 25 °C | - | - | 45 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G+}; $ T _j = 25 °C | - | - | 60 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C | - | - | 40 | mA |
| V _T | on-state voltage | I _T = 10 A; T _j = 25 °C | - | 1.3 | 1.65 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic ch | aracteristics | · · · | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 200 | - | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | $V_D = 400 \text{ V}; \text{ T}_j = 95 \text{ °C}; \text{ dI}_{com}/\text{dt} = 3.6 \text{ A}/\text{ms}; \text{ I}_T = 8 \text{ A}; \text{ gate open circuit}$ | 10 | - | - | V/µs |



10. Package outline



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11. Legal information

Data sheet status

| Document status [1][2] | Product status [<u>3]</u> | Definition |
|--------------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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- [2] The term 'short data sheet' is explained in section "Definitions".
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